

Features

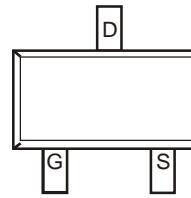
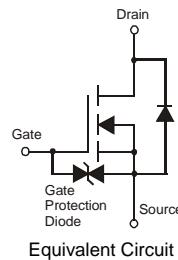
- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **ESD Protected Up To 2kV**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish – Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208 e3
- Terminal Connections: See Diagram
- Weight: 0.002 grams (approximate)



SOT523



Top View

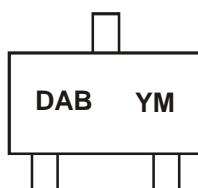
Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|--------|------------------|
| DMN5L06TK-7 | SOT523 | 3000/Tape & Reel |

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



DAB = Product Type Marking Code

YM = Date Code Marking

Y = Year (ex: T = 2006)

M = Month (ex: 9 = September)

Date Code Key

| Year | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 | | | | | |
|-------|------|------|------|------|------|------|------|-----|-----|-----|-----|-----|
| Code | T | U | V | W | X | Y | Z | | | | | |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Value | Units |
|------------------------|------------|----------|-------|
| Drain-Source Voltage | V_{DSS} | 50 | V |
| Gate-Source Voltage | V_{GSS} | ± 20 | V |
| Drain Current (Note 5) | Continuous | I_D | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Units |
|---|-----------------|-------------|-------|
| Total Power Dissipation (Note 5) | P_D | 150 | mW |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$ | 833 | °C/W |
| Operating and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | °C |

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------------|-------------|-------------------|-------------------|---------------------------|--|
| OFF CHARACTERISTICS (Note 6) | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | 50 | — | — | V | $V_{GS} = 0\text{V}, I_D = 10\mu\text{A}$ |
| Zero Gate Voltage Drain Current @ $T_C = +25^\circ\text{C}$ | I_{DSS} | — | — | 60 | nA | $V_{DS} = 50\text{V}, V_{GS} = 0\text{V}$ |
| Gate-Body Leakage | I_{GS} | — | — | 1 500 50 | μA nA nA | $V_{GS} = \pm 12\text{V}, V_{DS} = 0\text{V}$ $V_{GS} = \pm 10\text{V}, V_{DS} = 0\text{V}$ $V_{GS} = \pm 5\text{V}, V_{DS} = 0\text{V}$ |
| ON CHARACTERISTICS (Note 6) | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | 0.49 | — | 1.2 | V | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ |
| Static Drain-Source On-Resistance | $R_{DS(\text{ON})}$ | — — — | 1.8 1.5 1.2 | 3.0 2.5 2.0 | Ω | $V_{GS} = 1.8\text{V}, I_D = 50\text{mA}$ $V_{GS} = 2.5\text{V}, I_D = 50\text{mA}$ $V_{GS} = 5.0\text{V}, I_D = 50\text{mA}$ |
| On-State Drain Current | $I_{D(\text{ON})}$ | 0.5 | 1.4 | — | A | $V_{GS} = 10\text{V}, V_{DS} = 7.5\text{V}$ |
| Forward Transconductance | $ Y_{fs} $ | 200 | — | — | mS | $V_{DS} = 10\text{V}, I_D = 0.2\text{A}$ |
| Source-Drain Diode Forward Voltage | V_{SD} | 0.5 | — | 1.4 | V | $V_{GS} = 0\text{V}, I_S = 115\text{mA}$ |
| DYNAMIC CHARACTERISTICS | | | | | | |
| Input Capacitance | C_{iss} | — | — | 50 | pF | $V_{DS} = 25\text{V}, V_{GS} = 0\text{V}$ $f = 1.0\text{MHz}$ |
| Output Capacitance | C_{oss} | — | — | 25 | pF | |
| Reverse Transfer Capacitance | C_{rss} | — | — | 5.0 | pF | |

Notes: 5. Device mounted on FR-4 PCB.

6. Short duration pulse test used to minimize self-heating effect.

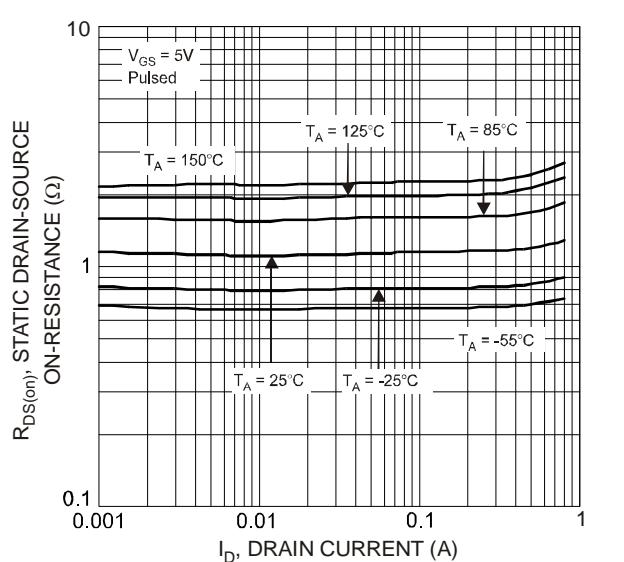
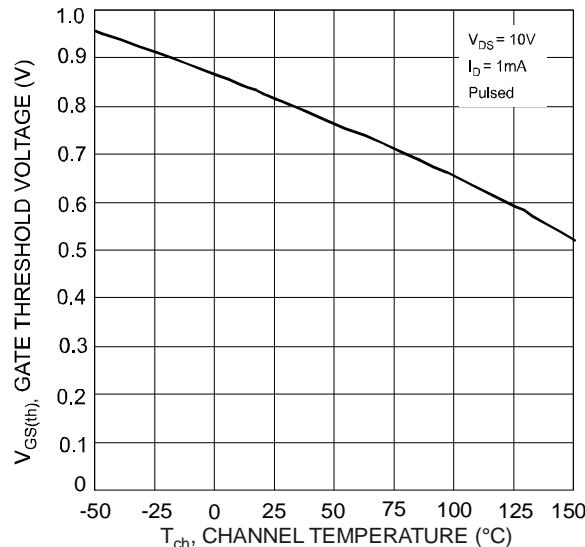
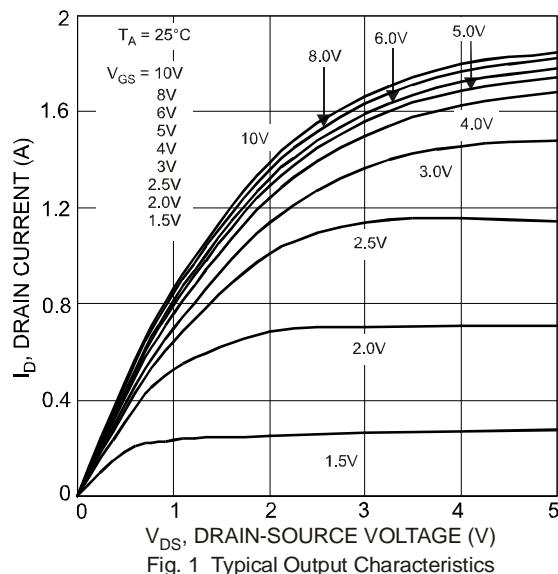


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current

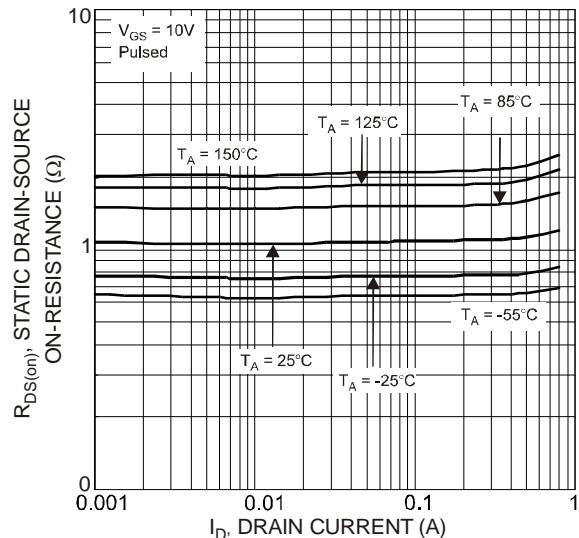
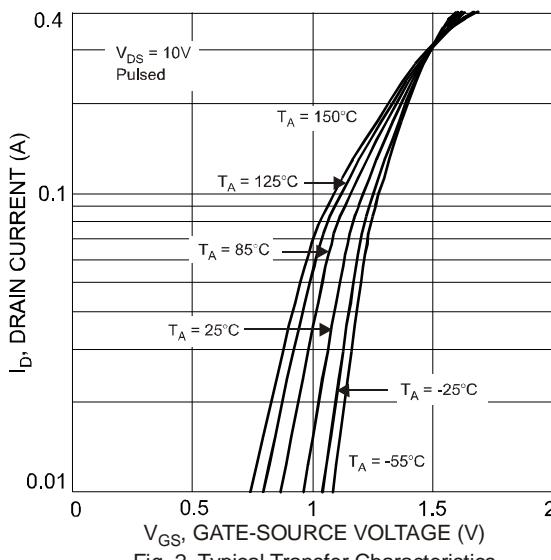
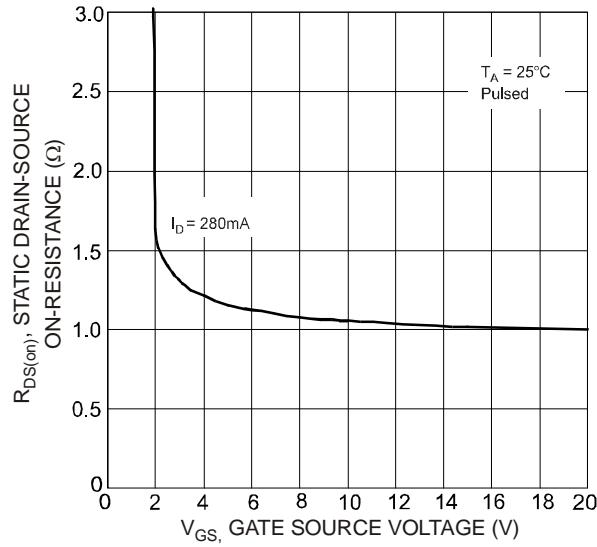


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current



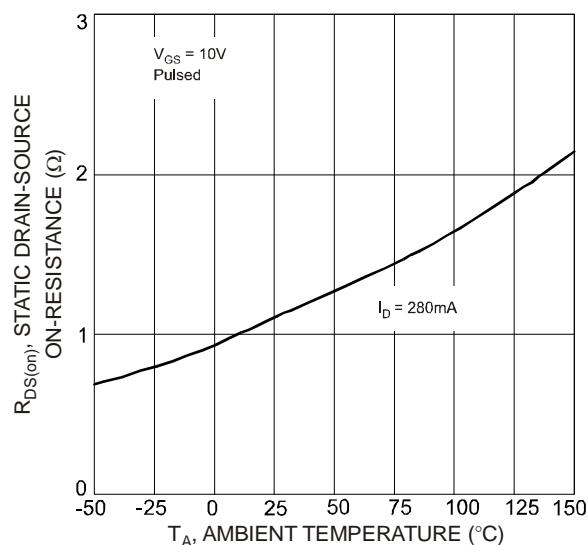


Fig. 7 Static Drain-Source On-State Resistance vs. Ambient Temperature

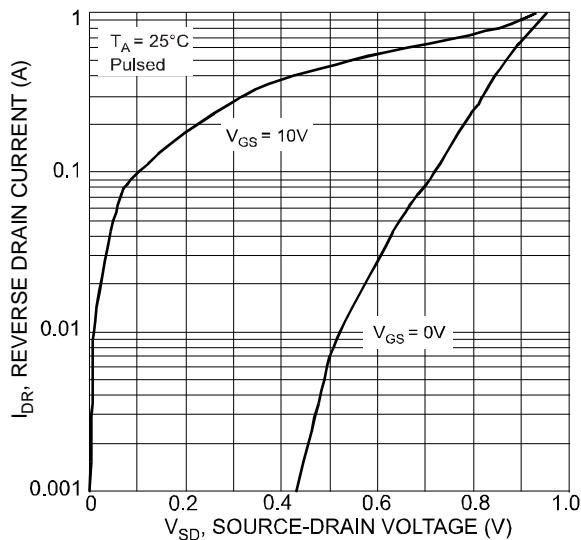


Fig. 9 Reverse Drain Current vs. Source-Drain Voltage

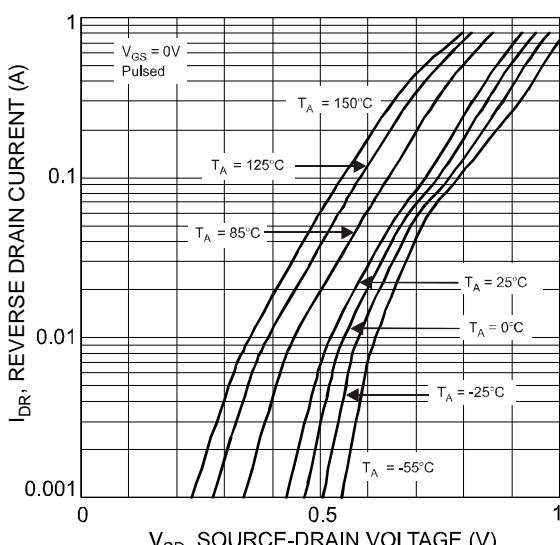


Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

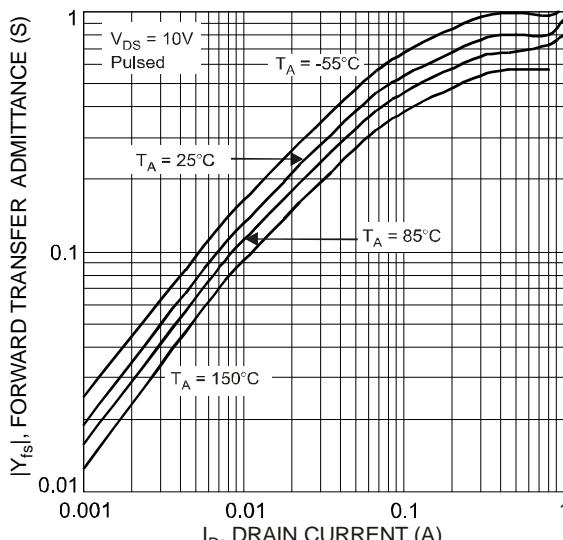
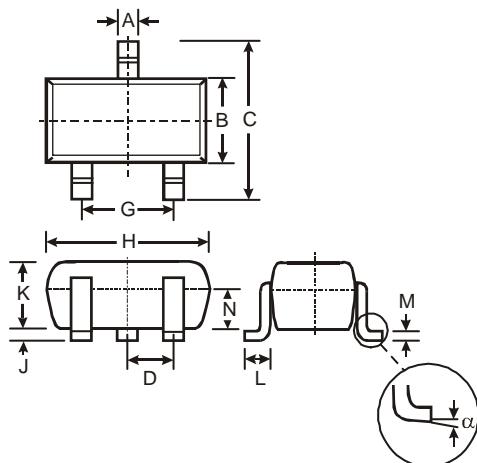


Fig. 10 Forward Transfer Admittance vs. Drain Current

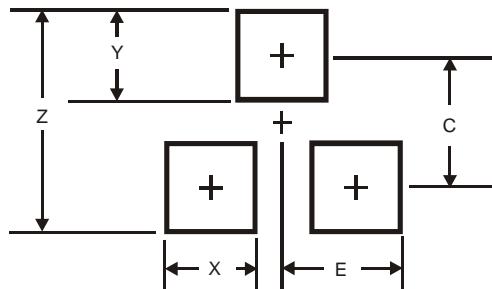
Package Outline Dimensions



| SOT523 | | | |
|----------|------|------|------|
| Dim | Min | Max | Typ |
| A | 0.15 | 0.30 | 0.22 |
| B | 0.75 | 0.85 | 0.80 |
| C | 1.45 | 1.75 | 1.60 |
| D | — | — | 0.50 |
| G | 0.90 | 1.10 | 1.00 |
| H | 1.50 | 1.70 | 1.60 |
| J | 0.00 | 0.10 | 0.05 |
| K | 0.60 | 0.80 | 0.75 |
| L | 0.10 | 0.30 | 0.22 |
| M | 0.10 | 0.20 | 0.12 |
| N | 0.45 | 0.65 | 0.50 |
| α | 0° | 8° | — |

All Dimensions in mm

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 1.8 |
| X | 0.4 |
| Y | 0.51 |
| C | 1.3 |
| E | 0.7 |

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